RFSA2013

VOLTAGE CONTROLLED ATTENUATOR

rfmd.com

Package Style: QFN, 16-Pin, 0.9mm x 3mm x 3mm



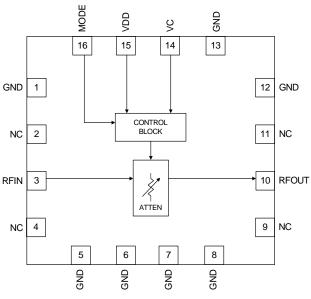


Features

- Patented Circuit Architecture
- Broadband 50MHz to 6000MHz Frequency Range
- 30dB Attenuation Range
- +50dBm IIP3 Typical
- +80dBm IIP2 Typical
- High 1dB Compression Point >+30dBm
- Low Supply Current 1mA Typical
- 5V Power Supply
- Linear in dB Control Characteristic
- Internal Temperature Compensation
- Class 1C ESD (1000V)
- 3.3V Version Available (RFSA2023)
- Complete Solution in a Small 3mm x 3mm, QFN Package

Applications

- Cellular, 3G Infrastructure
- WiBro, WiMax, LTE
- Microwave Radio
- High Linearity Power Control



Functional Block Diagram

Product Description

RFMD's RFSA2013 is a fully monolithic analog voltage controlled attenuator (VCA) featuring exceptional linearity over a typical temperature compensated 30dB gain control range. It incorporates a revolutionary new circuit architecture to solve a long standing industry problem: high IP3, high attenuation range, low DC current, broad bandwidth and temperature compensated linear in dB control voltage characteristic. This voltage controlled attenuator is controlled by a single positive control voltage with on chip DC conditioning circuitry. The slope of the control voltage versus gain is selectable. The RFSA2013 draws a very low 1mA current and is packaged in a small 3mm x 3mm QFN. This attenuator is matched to 50Ω over its rated control range and frequency with no external matching components required. Typical VCA's in this performance category have poor inherent attenuation versus temperature and poor nonlinear attenuation versus control voltage characteristics. To correct these shortcomings, other VCA's require extensive off chip analog support circuitry that consume valuable PCB area and additional DC power. This game changing product incorporates the complete solution in a small 3mm x 3mm QFN package that reduces the footprint by 20X in area and reduces the DC power by 10X over conventional PIN diode approaches.

Ordering Information

RFSA2013SR 7" Sample reel with 100 pieces RFSA2013SQ Sample bag with 25 pieces RFSA2013TR7 7" Reel with 2500 pieces

RFSA2013PCK-410 50MHz to 6000MHz PCBA with 5-piece sample bag

Optimum Technology Matching® Applied					
☐ GaAs HBT	☐ SiGe BiCMOS	☐_GaAs pHEMT	☐ GaN HEMT		
☐ GaAs MESFET	☐ Si BiCMOS	▼ Si CMOS	☐ BiFET HBT		
☐ InGaP HBT	☐ SiGe HBT	☐ Si BJT			

RFSA2013



Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (V _{DD})	-0.5 to +6	V
Control Voltage (V _C)	-0.5 to +6	V
Mode Pin Voltage (MODE)	-0.5 to +6	V
RF Input Power	+30	dBm
Storage Temperature	-65 to +150	°C
Junction Temperature	+125	°C
ESD Rating Human Body Model (HBM)	1000	V



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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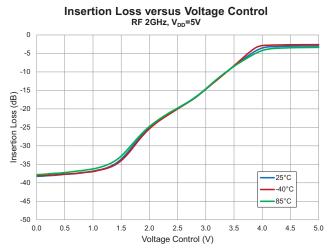


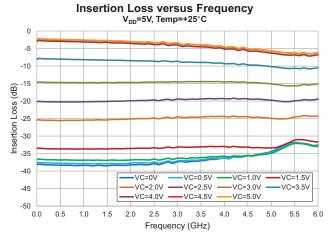
RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000 ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

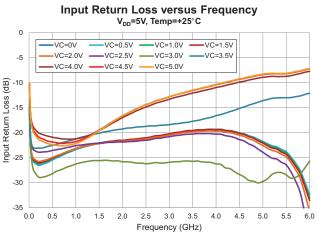
Baramatar	S	pecificati	on	Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
General						
Supply Voltage	4.75	5	5.25	V		
Supply Current		1		mA		
Operating Temperature (RF Input Power Handling Derates Above 85 °C)	-40		+105	°C		
Thermal Resistance		45		°C/W	RF input must be RFIN pin	
RF Input Power at 85°C			27	dBm	RF input must be RFIN pin	
RF Performance		,	<u>'</u>	<u>'</u>		
Frequency Range	50		6000	MHz		
Minimum Insertion Loss		2.6	3.5	dB		
Gain Control Range	30	33.2		dB	DC to 4GHz	
Gain versus Temperature		1.7		dB	Peak to peak gain variation over temperature for fixed control voltage	
Return Loss		15		dB		
Relative Phase		16.2		Deg	Insertion phase at 15dB attenuation relative to minimum insertion loss	
Input 1dB Compression Point		30		dBm		
Input IP3	45	50		dBm	PIN + (IM3 _{dBC} /2)	
Input IP2		80		dBm	PIN + IM2 _{dBC} , IM2 is F1+F2	
Input IH2		85		dBm	PIN + H2 _{dBC} , H2 is second harmonic	
Input IH3		55		dBm	PIN + (H3 _{dBC} /2), H3 is third harmonic	
Control						
Voltage Control Range, Positive Attenuation Slope	0.5		4.5	V	4.5V control voltage is lowest insertion loss, MODE pin high	
Voltage Control Range, Negative Attenuation Slope	0		3.3	V	OV control voltage is lowest insertion loss, MODE pin low	
Voltage Control Pin Current (MODE High)		37		μΑ	VC Pin at 5V	
Voltage Control Pin Current (MODE Low)		24		μΑ	VC Pin at 3.3V	
MODE Pin Logic Low			0.4	V		
MODE Pin Logic High	1			V		
Settling Time		15		μsec	1dB attenuation change settling within 0.1dB	

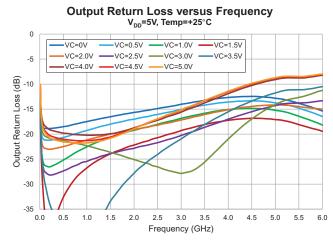
Note: Typical performance at nominal conditions unless otherwise noted: Supply voltage = 5.0V, Operating temperature = 25 °C, RF Frequency 2GHz

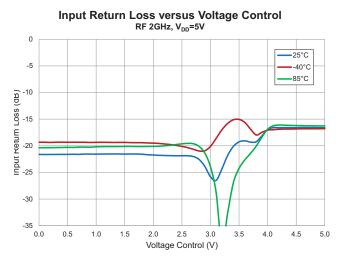


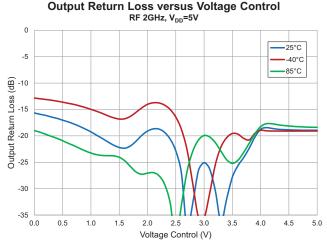






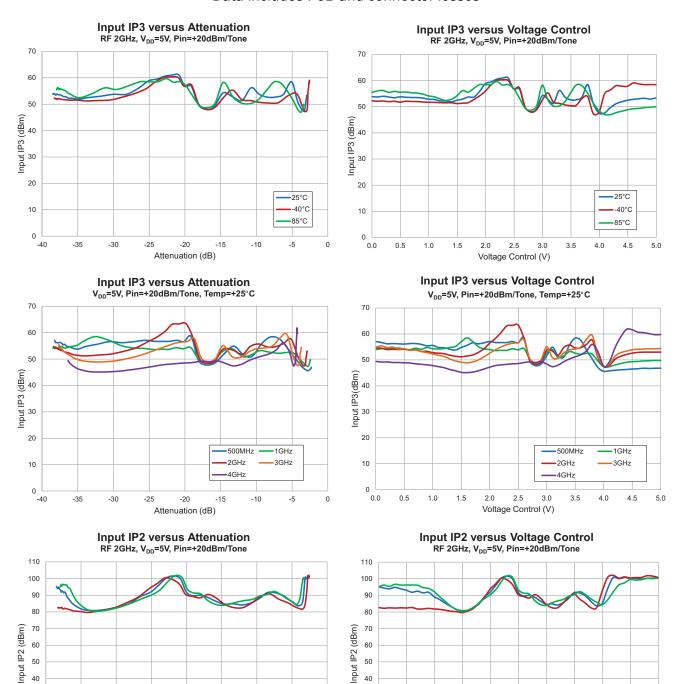








Data includes PCB and connector losses



40

30

20

10

0.0

0.5

1.0

2.0

2.5

Voltage Control (V)

3.5

4.0

-25°C

-40°C

85°C

-5

-10

-20

Attenuation (dB)

40

30

20

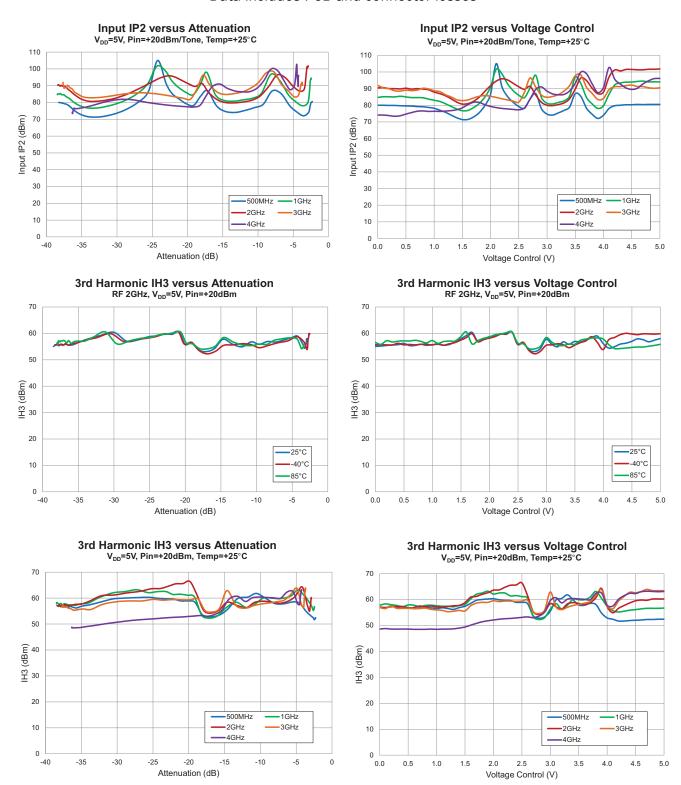
10

25°C

85°C

4.5

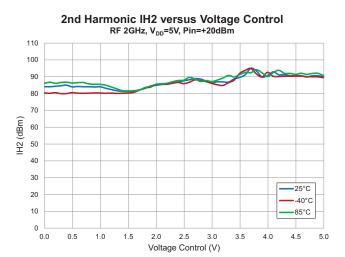


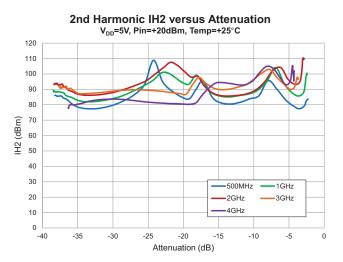


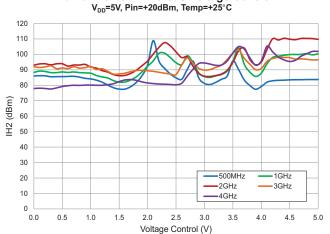


Data includes PCB and connector losses

2nd Harmonic IH2 versus Attenuation RF 2GHz, V_{DD} =5V, Pin=+20dBm 110 100 90 80 70 IH2 (dBm) 60 50 40 30 25°C 20 -40°C 10 -85°C -40 -5 -35 -15 Attenuation (dB)

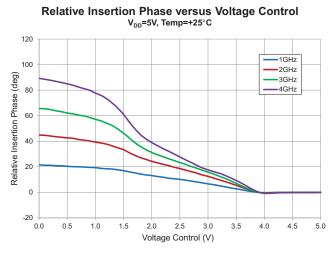


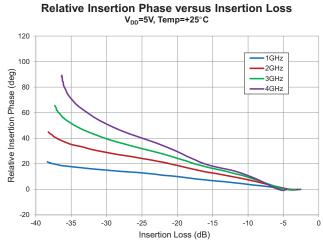


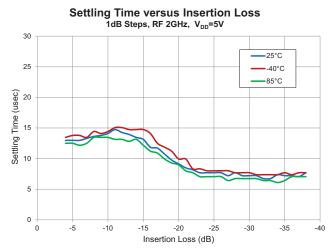


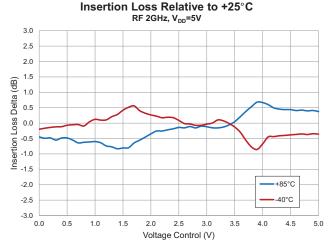
2nd Harmonic IH2 versus Voltage Control



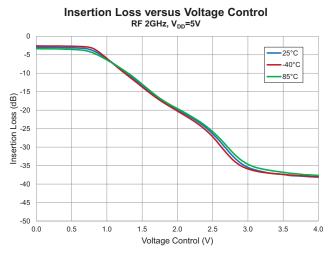


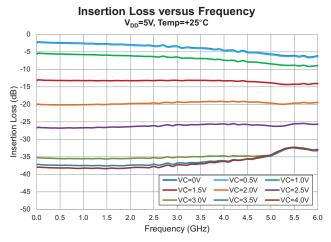


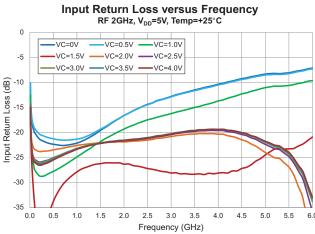


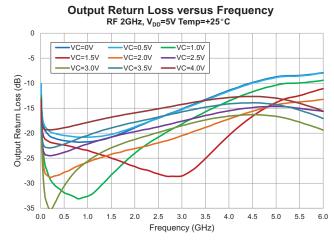


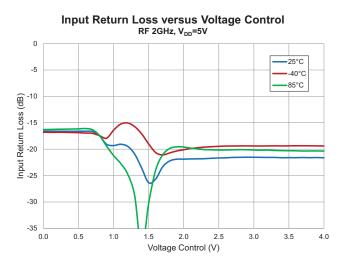


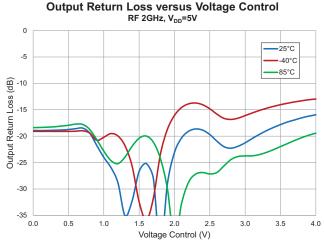




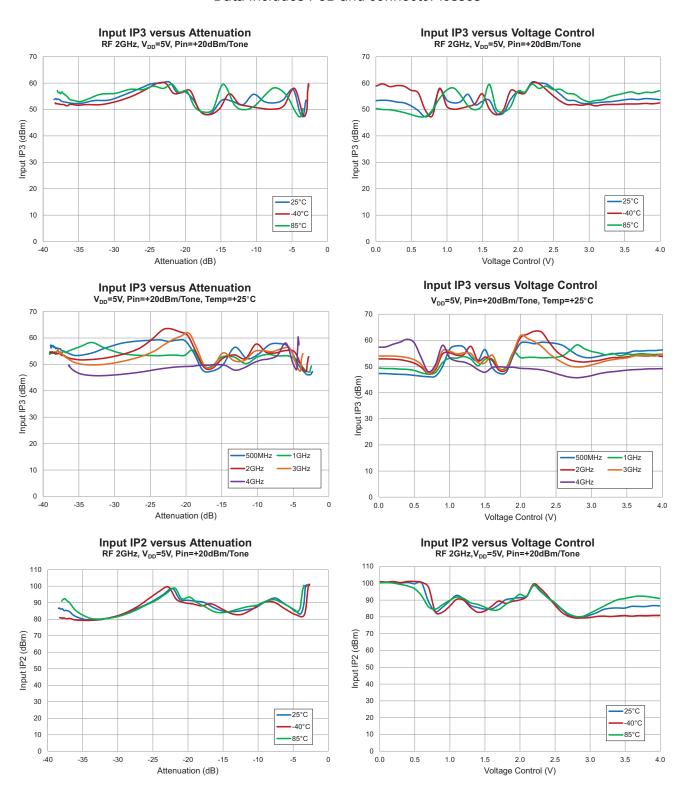




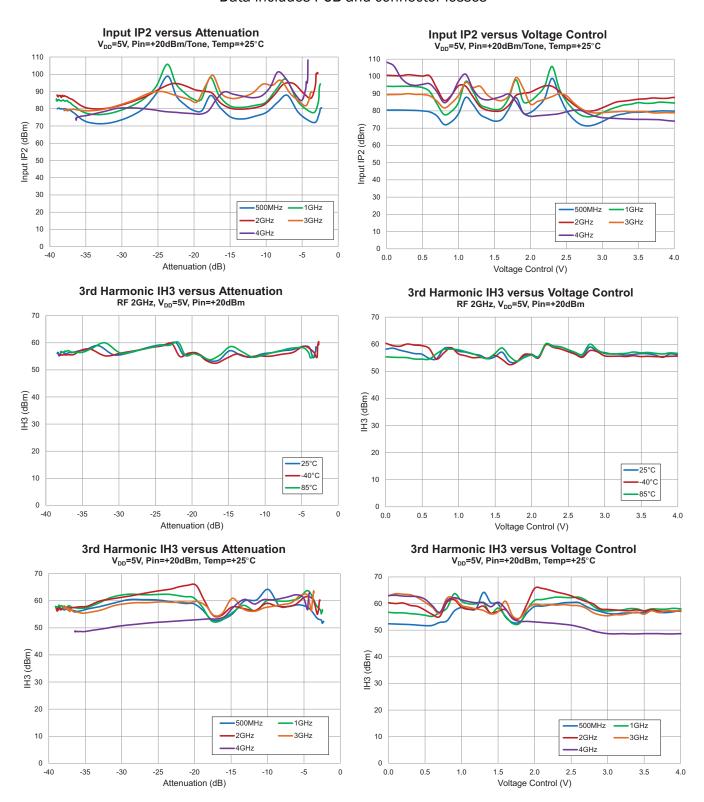




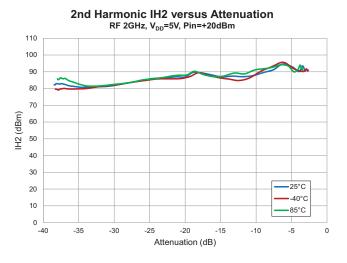


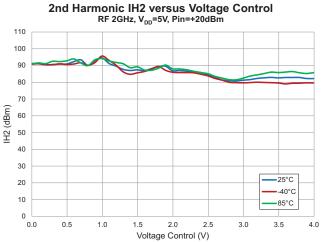


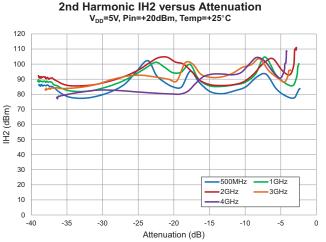


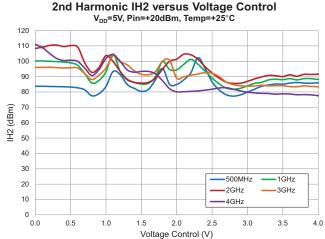




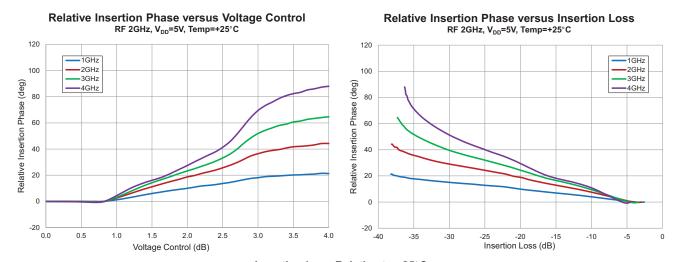


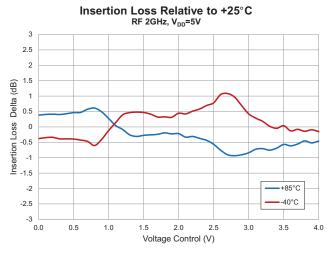






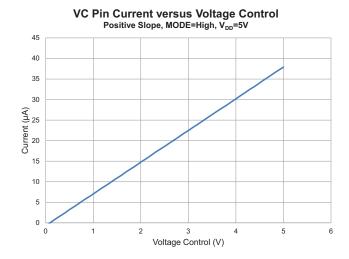


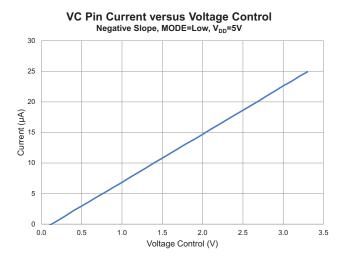






Voltage Control Pin Current Performance



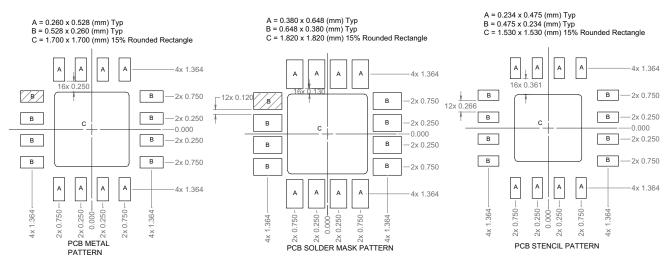




Pin Names and Descriptions

Pin	Name	Description	
1	GND	Ground Pin	
2	NC	No Connection. Do Not Connect to PC Board Ground Plane.	
3	RFIN	RF Input. Use External DC Block. RF input must be this pin to insure linearity and thermal resistance specifications.	
4	NC	No Connection. Do Not Connect to PC Board Ground Plane.	
5	GND	Ground Pin	
6	GND	Ground Pin	
7	GND	Ground Pin	
8	GND	Ground Pin	
9	NC	No Connection. Do Not Connect to PC Board Ground Plane.	
10	RFOUT	RF Output. Use External DC Block. RF output must be this pin to insure linearity and thermal resistance specifications.	
11	NC	No Connection. Do Not Connect to PC Board Ground Plane.	
12	GND	Ground Pin	
13	GND	Ground Pin	
14	VC	Attenuator Control Voltage	
15	VDD	Supply Voltage (5V)	
16	MODE	Attenuation Slope Control Set to Logic Low to Enable Negative Attenuation Slope. Set to Logic High to Enable Positive Attenuation Slope.	
GND	GND	Exposed Package Ground Paddle is RF and DC Ground	

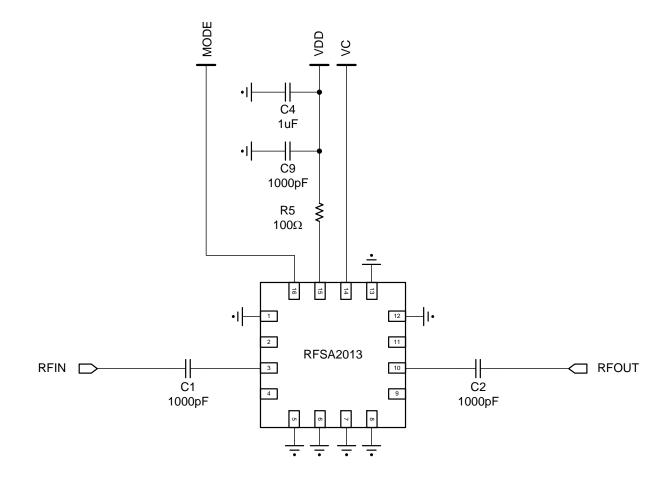
PCB Patterns



Thermal vias for center slug "C" should be incorporated into the PCB design. The number and size of thermal vias will depend on the application, the power dissipation and the electrical requirements. Example of the number and size of vias can be found on the RFMD evaluation board layout.

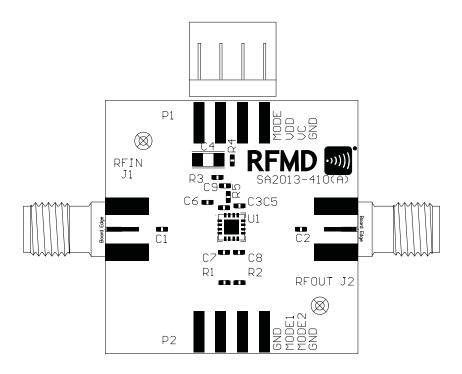


Evaluation Board Schematic





Evaluation Board Assembly Drawing



Evaluation Board Bill of Materials (BOM)

Description	Reference Designator	Manufacturer	Manufacturer's P/N
Voltage Controlled Attenuator VCA, 5V	U1	RFMD	RFSA2013
CONN, SMA, END LNCH, MINI, FLT, 0.068"	J1-J2	Emerson Network Power	142-0741-851
CONN, HDR, SR, 4-PIN, 0.100", T/H'	P1	MOLEX	22-28-4043
PCB, SA2013-410		DDI	SA2013-410
CAP, 1000pF, 10%, 25V, X7R, 0402	C1-C2, C9	Murata Electronics	GRM155R71H102KA01D
CAP, 1µF, 10%, 16V, X7R, 1206	C4	Murata Electronics	GRM31MR71E105KC01L
RES, 100Ω, 5%, 1/16W, 0402	R5	Kamaya, Inc	RMC1/16S-101JTH
DNP	C3, C5-C8	N/A	N/A
DNP	R1-R4	N/A	N/A
DNP	P2	N/A	N/A

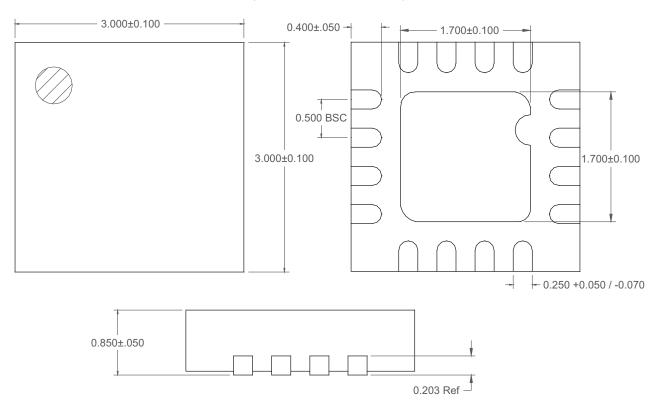
Notes:

- 1. Manufacturers' P/Ns are subject to change by the manufacturers following the issue of this document and are thereby included for reference only.
- 2. Contact RFMD Corporate Engineering Materials with questions regarding specific Manufacturers' P/Ns.



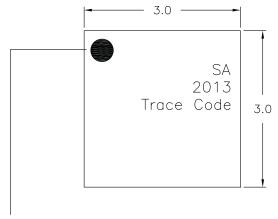
Package Drawing

(0.9mm x 3mm x 3mm)



Branding Diagram

(0.9mm x 3mm x 3mm)



Pin 1 Indicator

Trace Code to be assigned by SubCon